Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
SI	1	("20040252488").PN.	US-PGPUB; USPAT	OR	OFF	2006/04/27 16:31
S2	933	(313/512).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/11/02 15:10
S3	4	(light adj emitting) same (ceiling with tile) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:02
S4	54	(use with lighting).clm.	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:04
S10	3813	(substrate same (insulation or dielectric) same electrode) and (light with emitting) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:41
S11	8	S10 and ((silicon or si) same nanoparticle)	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:45
S12	4	S11 and binder	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:42
S13	4	S12 and transparent	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:43
S14	39	S10 and nanoparticle	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:47
S15	2940	S10 and @ad<"20020401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:48
S16	0	S15 and ((electron and hole) adj (transport and barrier))	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:49
S17	100	S15 and ((electron and hole) adj transport)	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 17:00
S18	0	S15 and ((electron and hole) adj barrier)	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:49
S19	28	S17 and reflective	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 17:32
S20	5	S17 and (reflective adj layer)	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:59

S21	0	(("US3,842,306") or ("US4,047,069") or ("US4,330,691") or ("US4,642,951") or ("US4,890,033") or ("US4,923, 032") or ("US4,965,485") or ("US5,073,805") or ("US5,142,343") or ("US5,293,050") or ("US5,354,707") or ("US5,422,489") or ("US5,438,234") or ("US5,516,577") or ("US5,536,949") or ("US5,537,000") or ("US5,552,665") or ("US5,813,753") or ("US5,850,064") or ("US5,852,346") or ("US5,882,779") or ("US5,959,316") or ("US5,962,863") or ("US5,977,565") or ("US5,990,479") or ("US6,068,907") or ("US6,069,440") or ("US6,117.514") or ("US6,157,047") or ("US6,157,187") or ("US6,251,303") or ("US6,252,254") or ("US6,252,915") or ("US6,268,041") or ("US6,397.531") or ("US6,336,837") or ("US6,341,7019") or ("US6,441,551") or ("US6,441,551") or ("US6,501,091") or ("US6,501,102") or ("US6,602,731") or ("US6,660,410") or ("US6,632,694") or ("US6,649,138") or ("US6,669,512") or ("US6,669,158") or ("US6,669,158") or ("US6,701,368") or ("US6,669,158") or ("US6,701,368")).PN. or ((US2001/0000622) or (US2001/0040232) or (US2002/0153830) or (US2002/0152704) or (US2003/003300) or (US2003/0042850) or (US2003/003300) or (US2003/0042850) or (US2003/0227249) or (US2004/0007169) or (US2004/0033345)).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/11/02 16:55
S22	65	(("3,842,306") or ("4,047,069") or ("4,330,691") or ("4,642,951") or ("4,890,033") or ("4,923,032") or ("4,965,485") or ("5,073,805") or ("5,142,343") or ("5,293,050") or ("5,354,707") or ("5,422,489") or ("5,438,234") or ("5,552,665") or ("5,813,753") or ("5,850,064") or ("5,852,346") or ("5,882,779") or ("5,959,316") or ("5,962,863") or ("5,977,565") or ("5,990,479") or ("6,068,907") or ("6,069,440") or ("6,117.514") or ("6,157,047") or ("6,175,187") or ("6,207,229") or ("6,215,881") or ("6,245,259") or ("6,251,303") or ("6,252,254") or ("6,252,915") or ("6,389,771") or ("6,397.531") or ("6,441,551") or ("6,441,719") or ("6,501,102") or ("6,504,179") or ("6,508,573") or ("6,515,314") or ("6,521,915") or ("6,585,947") or ("6,602,731") or ("6,608,30") or ("6,660,410") or ("6,661,029") or ("6,669,158") or ("6,692,512") or ("6,602,701") or ("6,602,701") or ("6,602,701") or ("6,602,701") or ("6,601,029") or ("6,669,158") or ("6,692,512") or ("6,601,029") or ("6,669,158") or ("6,602,701") or ("6,701,686")).PN. or ((2001/0000622) or (2001/0040232) or (2002/018632) or (2002/0152704) or (2003/003614) or (2003/0034486) or (2003/0042850) or (2003/0047816) or (2003/0034486) or (2003/0042850) or (2003/0033345)). CCLS.	US-PGPUB; USPAT	OR	OFF	
S23	4	S22 and (substrate same (insulation or dielectric) same electrode)	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 16:58

S24	1	"20030057821".pn.	US-PGPUB;	OR	ON	2005/11/02 17:10
52.	•	20050057021 .pm.	USPAT; USOCR			2003/11/02 17:10
S25	1	"6693512".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 17:32
S26	1	("20030067265").PN.	US-PGPUB; USPAT	OR	OFF	2005/11/02 19:52
S27	702	(light adj emitting) and ((electron and hole) with barrier) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 19:54
S28	29	(light adj emitting) and ((electron and hole) adj barrier) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/02 19:55
S29	4	((light adj emitting) same ((electron and hole) adj barrier) and semiconductor) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 11:08
S30	0	2004/0036130.pn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 11:08
S31	1	"20040036130".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 11:28
S32	1	"20020025391".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 15:01
S33	54	(ceiling adj tile) and (light\$3 with (emergency or in\$door or track or (airplane with interior))) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 15:03
S34	9	(ceiling adj tile) same (light\$3 with (emergency or in\$door or track or (airplane with interior))) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 15:04
S35	591	(ceiling) same (light\$3 with (emergency or in\$door or track or (airplane with interior))) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 15:04
S36	396	(ceiling) with (light\$3 with (emergency or in\$door or track or (airplane with interior))) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 15:13
S37	3	(light\$3 with (emergency and in\$door and track and (airplane with interior))) and @ad<"20030401"	US-PGPUB; USPAT; USOCR	OR	ON	2005/11/03 15:13
S38	2224	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and ceiling	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 16:40
S39	50	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and (ceiling near2 tile)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 16:32

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		Little Scarcii IIIs	•			
S40	568	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and ceiling and (electrode cathod anode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 16:41
S41	63	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and ceiling and (electrode cathod anode) and (hole same electron same transport\$3 same inject\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 16:42
S42	43	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and ceiling and (electrode cathod anode) and (hole same electron same transport\$3 same inject\$3) and silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 18:20
S43	64	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and (silicon with nanoparticle)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 18:22
S44	19	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and (silicon with nanoparticle) and (nanoparticle with diameter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 21:50
S45	1282	(led oled oeld (light near2 emitting) electroluminescen\$2 el).clm. and (reflect\$3 adj layer).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 21:50
S46	757	S45 and @ad<"20030401"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/04/27 21:51
S47	2	10/814294	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/01/10 14:56
S48	73	((light near2 emitting) with device) and ((nanostructure nanoparticle) with ink)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/01/10 14:57
S49	39	S48 and @ad<"20040401"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/01/10 14:57

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060		#20020000CEE# #C01004C#	I via nanvin	0.0	021	
S50	4	"20030080677".pn. "6918946".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/07/28 15:31
S51	2	10/814294	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR .	ON	2007/07/28 15:39
S52	2758	((light near2 emitting) with (si silicon ge germanium semiconductor)) and ink	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/07/28 15:41
S53	41	((light near2 emitting) with (si silicon ge germanium semiconductor) with (nano nanotube nanoparticle nanostructure)) and ink	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/07/28 15:45
S54	10	S53 and @ad<"20030401"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/07/28 15:42
S55	13	((light near2 emitting) with (si silicon ge germanium semiconductor) with (nano nanotube nanoparticle nanostructure)) and ink and binder and solvent	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/07/28 15:46
S56	1	S55 and @ad<"20030401"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2007/07/28 15:46